DISCRETE SEMICONDUCTORS

DATA SHEET

PDTC144W series NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

Product data sheet Supersedes data of 2004 Mar 23 2004 Aug 17



NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V_{CEO}	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	47	_	kΩ
R2	bias resistor	22	_	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PACE	(AGE	MARKING CODE	PNP COMPLEMENT	
ITPE NUMBER	PHILIPS	PHILIPS EIAJ		PNP COMPLEMENT	
PDTC144WE	SOT416	SC-75	42	PDTA144WE	
PDTC144WEF	SOT490	SC-89	34	PDTA144WEF	
PDTC144WK	SOT346	SC-59	41	PDTA144WK	
PDTC144WM	SOT883	SC-101	DD	PDTA144WM	
PDTC144WS	SOT54 (TO-92)	SC-43	TC144W	PDTA144WS	
PDTC144WT	SOT23	-	*20 ⁽¹⁾	PDTA144WT	
PDTC144WU	SOT323	SC-70	*20 ⁽¹⁾	PDTA144WU	

Note

^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

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PDTC144W series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL		PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTC144WS	1 R1 R2 R2 R2 R2 R2 R2	1 2 3	base collector emitter
PDTC144WE PDTC144WK PDTC144WT PDTC144WU	Top view 1 R1 R2	1 2 3	base emitter collector
PDTC144WM	2 R1 R2 P2 P3	1 2 3	base emitter collector

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PDTC144W series

ORDERING INFORMATION

TYPE NUMBER	PACKAGE							
TYPE NUMBER	NAME	DESCRIPTION	VERSION					
PDTC144WE	_	plastic surface mounted package; 3 leads	SOT416					
PDTC144WEF	_	plastic surface mounted package; 3 leads	SOT490					
PDTC144WK	_	plastic surface mounted package; 3 leads	SOT346					
PDTC144WM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm	SOT883					
PDTC144WS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54					
PDTC144WT	_	plastic surface mounted package; 3 leads	SOT23					
PDTC144WU	_	plastic surface mounted package; 3 leads	SOT323					

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base	_	50	V
V _{EBO}	emitter-base voltage	open collector	_	10	V
Vi	input voltage				
	positive		_	+40	V
	negative		_	-10	V
Io	output current (DC)		_	100	mA
I _{CM}	peak collector current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	_	150	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

4

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

2004 Aug 17

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	_	_	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	_	_	110	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	60	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	_	150	mV
$V_{i(off)}$	input-off voltage	$I_C = 100 \mu A; V_{CE} = 5 V$	_	1.7	1.2	V
$V_{i(on)}$	input-on voltage	$I_C = 2 \text{ mA}; V_{CE} = 0.3 \text{ V}$	4	2.7	_	٧
R1	input resistor		33	47	61	kΩ
R2 R1	resistor ratio		0.37	0.47	0.57	
C _c	collector capacitance	$I_E = I_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	-	_	2.5	pF

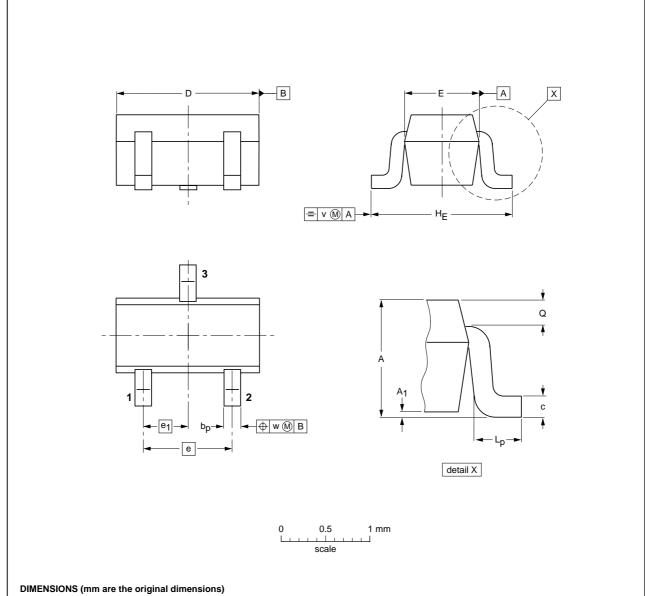
NPN resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 22 \text{ k}\Omega$

PDTC144W series

PACKAGE OUTLINES

Plastic surface-mounted package; 3 leads

SOT416



UNIT	Α	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	ø	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT416			SC-75			04-11-04 06-03-16

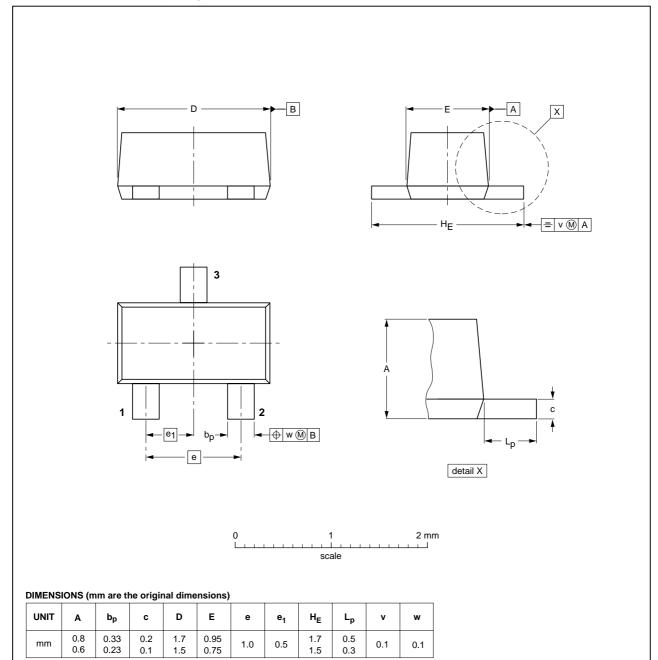
2004 Aug 17 6

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

Plastic surface-mounted package; 3 leads

SOT490



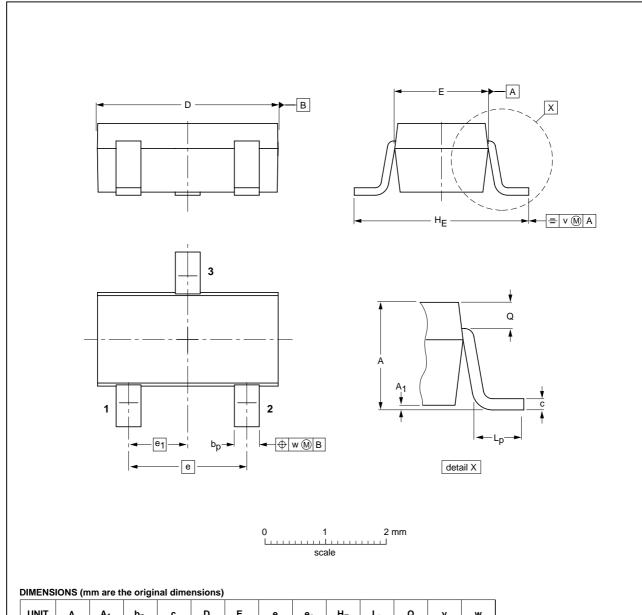
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1920E DATE	
SOT490			SC-89			05-07-28 06-03-16	

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

Plastic surface-mounted package; 3 leads

SOT346



UNII	Α	A ₁	ор	С	ט	E	е	e ₁	HE	Lp	Q	'	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

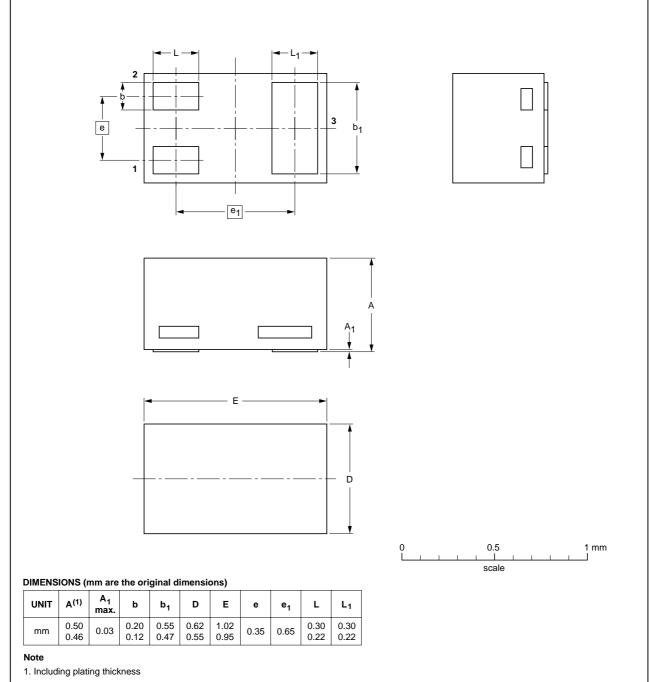
OUTLINE		REFER	EUROPEAN	ICCUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A			-04-11-11 06-03-16	

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



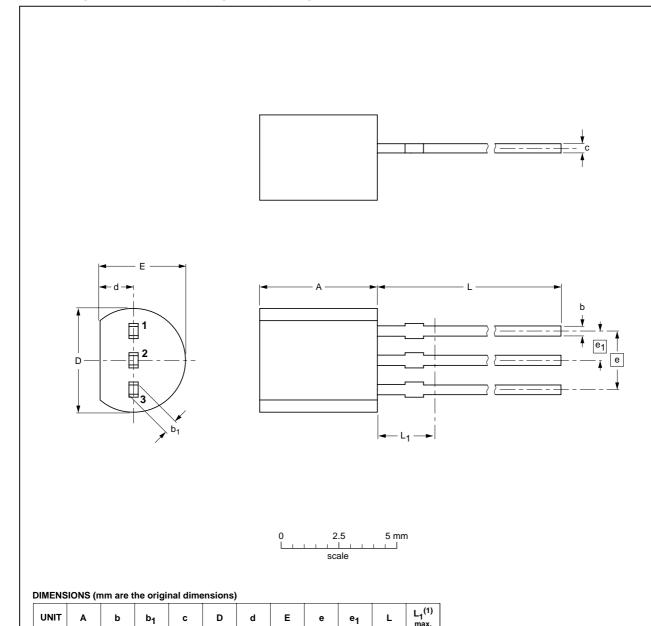
OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	JEITA PROJECTION	PROJECTION	ISSUE DATE
SOT883			SC-101			03-02-05 03-04-03

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



mm

0.48

0.40

5.0

0.66

0.55

0.45

0.38

4.8

4.4

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

1.7

1.4

4.2

3.6

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			04-06-28 04-11-16

1.27

2.54

14.5

12.7

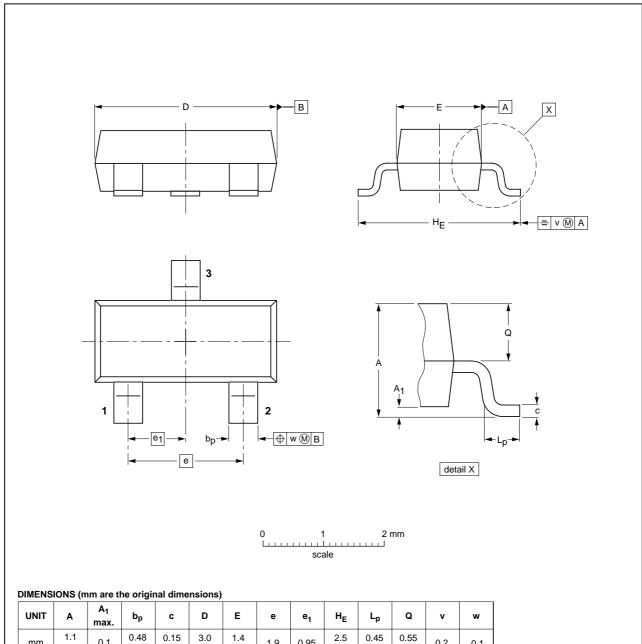
2.5

NPN resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, $R2 = 22 \text{ k}\Omega$

PDTC144W series

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE	OUTLINE REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				-04-11-04 06-03-16

0.2

0.1

1.9

2004 Aug 17 11

0.38

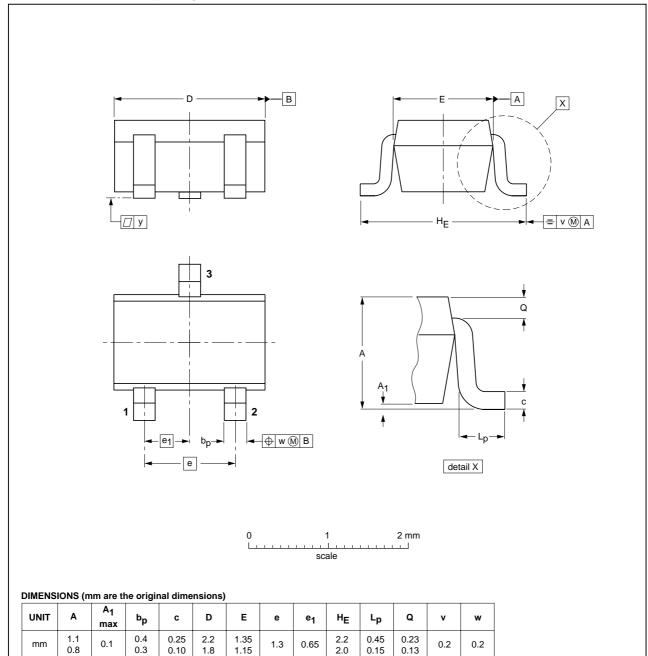
0.9

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

Plastic surface-mounted package; 3 leads

SOT323



OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT323			SC-70			04-11-04 06-03-16

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

PDTC144W series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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Contact information

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